

# Supporting Information

## Self-discharge mechanism of high voltage KVPO<sub>4</sub>F for K-ion batteries

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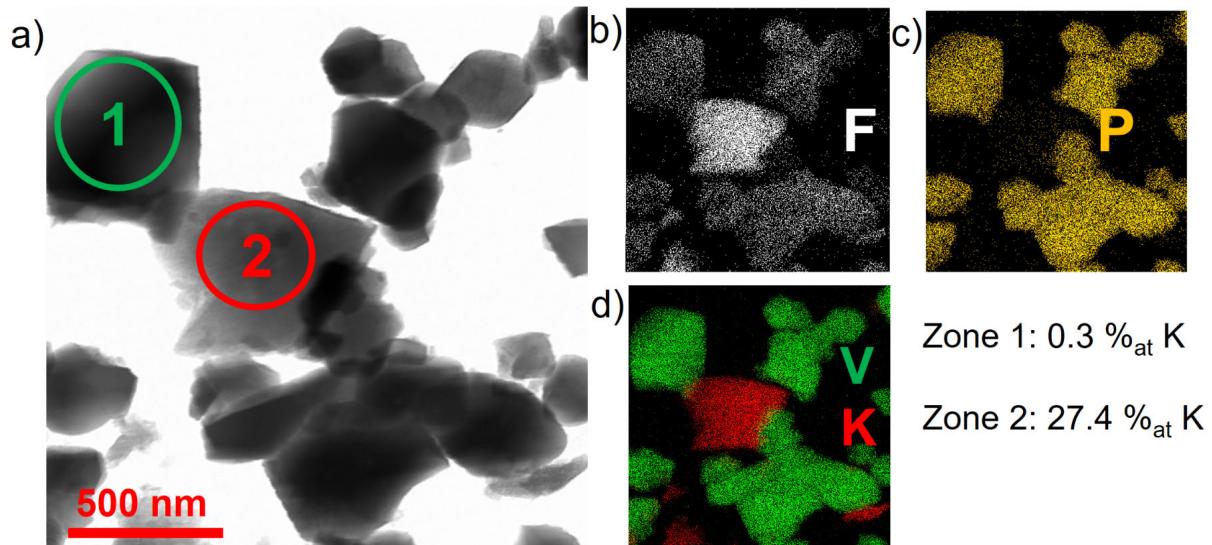
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**Figure S1:** EDX mapping of the sample obtained after chemical deintercalation KVPO<sub>4</sub>F: a) STEM image, b) EDX mapping of F, c) EDX mapping of P, d) EDX mapping of V (in green) and K (in red).

**Table S1:** Atomic parameters and first neighbour interatomic distances of K<sub>0</sub>VPO<sub>4</sub>F refined by the Rietveld method.

K <sub>0</sub> VPO <sub>4</sub> F	Pnан	Z=8		$\rho = 2.75 \text{ g/cm}^3$		
		a (Å)	b (Å)	c (Å)	occupancy	$B_{\text{iso}} (\text{\AA}^2)$
		12.504(1)	6.0875(5)	10.462(1)		
Wyckoff position		x/a	y/b	z/c		
V2 <sub>trans</sub>	4a	0	0	0	1	1.0(1)
V1 <sub>cis</sub>	4d	0.145(1)	¼	¾	1	1.2(2)
P1	4c	¼	0.070(2)	0	1	1.3(2)
P2	4d	-0.062(1)	¼	¼	1	1.3(2)
O1a	8e	0.246(2)	0.230(4)	-0.116(2)	1	1.2(2)
O2a	8e	0.149(1)	-0.067(2)	0.010(3)	1	1.2(2)
O1b	8e	-0.133(2)	0.051(4)	0.274(2)	1	1.2(2)
O2b	8e	0.010(2)	0.294(5)	0.367(2)	1	1.2(2)
F1	8e	0.028(2)	0.277(5)	0.626(2)	1	1.2(5)

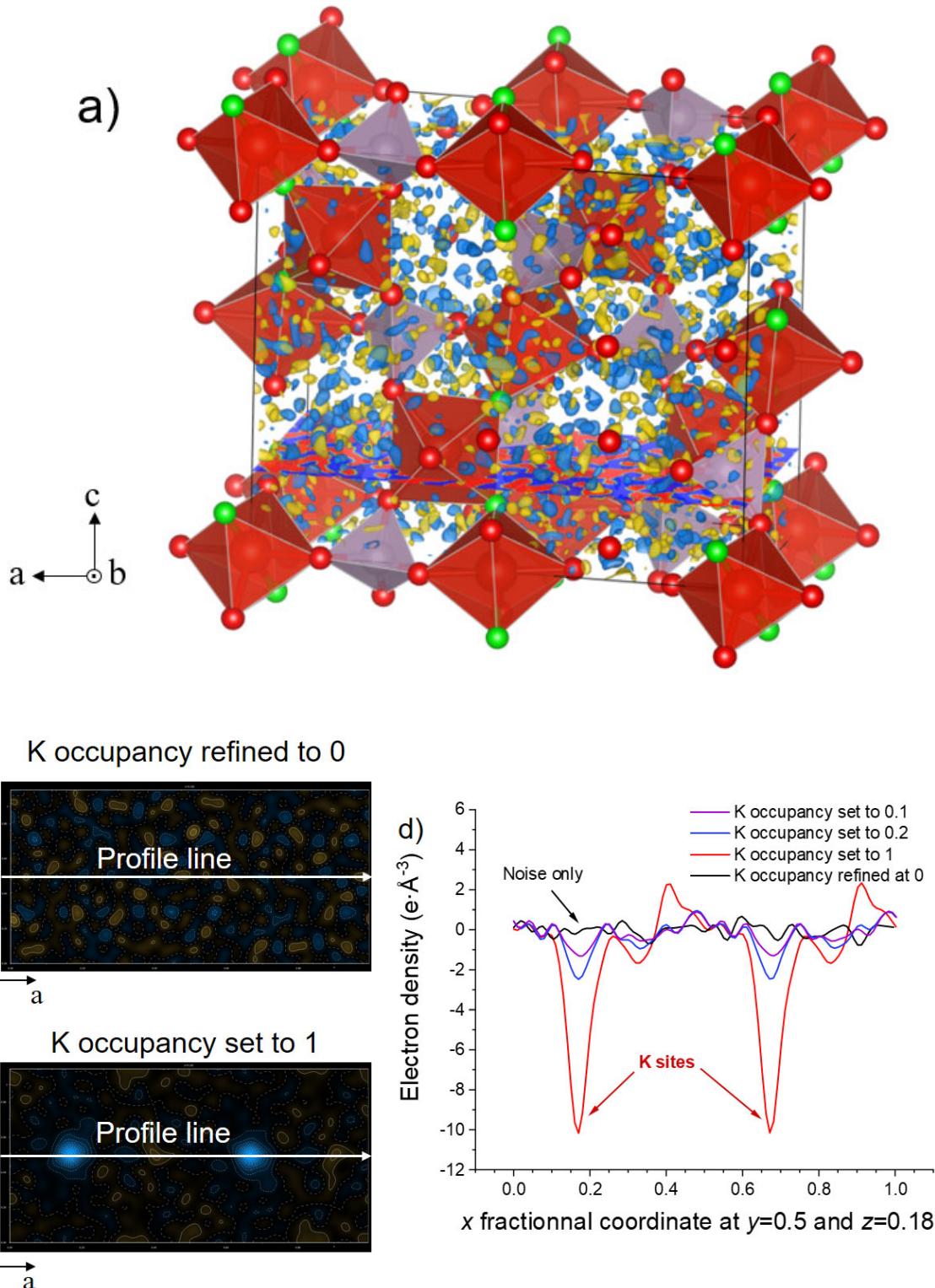
Bond	Distance (Å)*	Bond	Distance (Å)*
V2–O2a	1.90 × 2	V1–O1a	1.90 × 2
V2–O2b	1.88 × 2	V1–O1b	1.85 × 2
V2–F1	1.93 × 2	V1–F1	1.95 × 2
P1–O1a	1.55 × 2	P2–O1b	1.53 × 2
P1–O2a	1.53 × 2	P2–O2b	1.54 × 2
V1(O <sub>4</sub> F <sub>2</sub> )		V2(O <sub>4</sub> F <sub>2</sub> )	
Site distortion (10 <sup>-4</sup> )	17.2		4.4

\*rounded to 10<sup>-2</sup> Å

The site distortion depicts the deviation from a regular octahedron and was calculated using the following formula:

$$\Delta = \frac{1}{6} \sum_{i=1}^6 \frac{(d_i - \bar{d})^2}{\bar{d}^2}$$

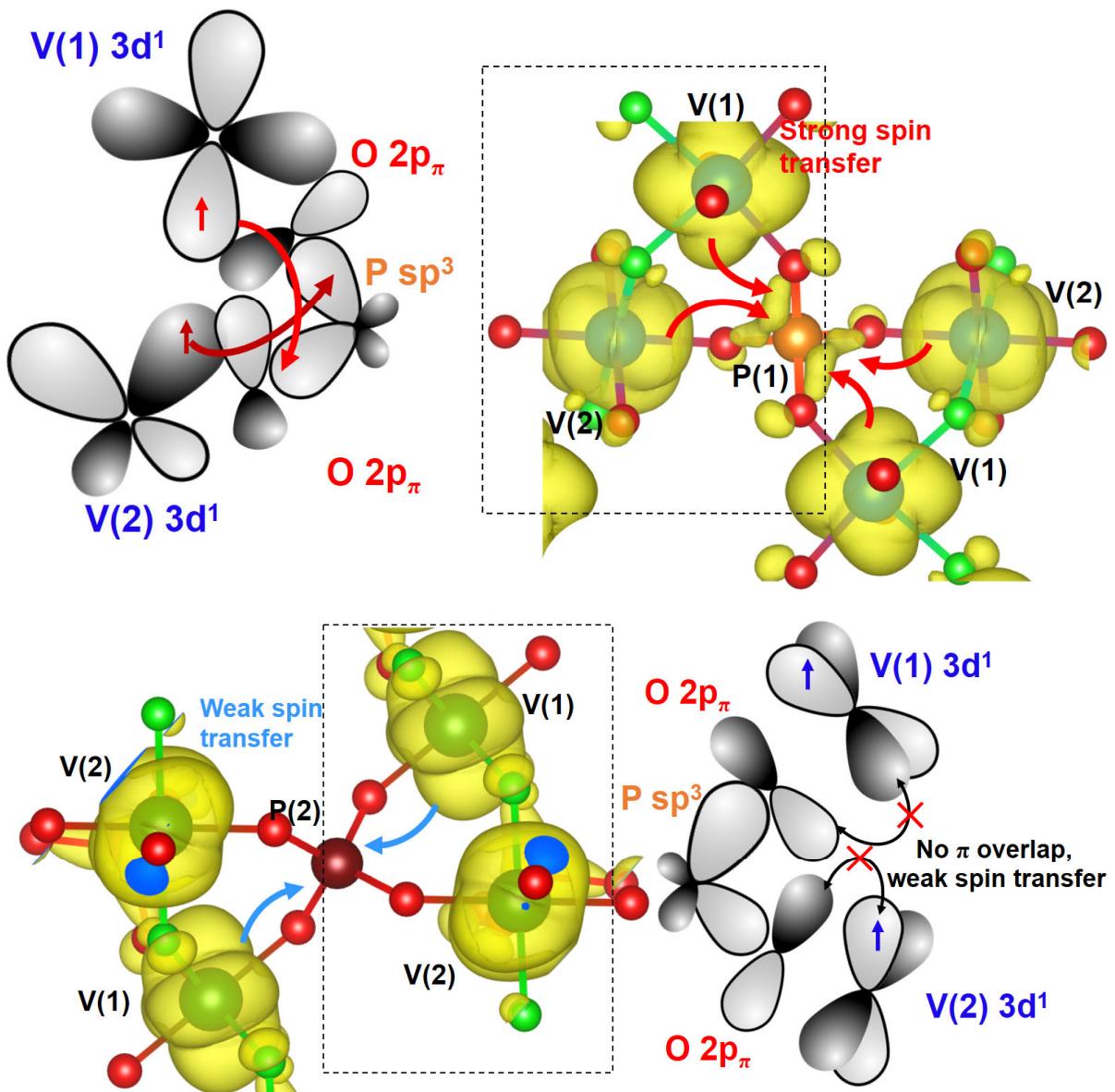
Where  $d_i$  corresponds to each V–X bond of the octahedron and  $\bar{d}$  is the average bond length.



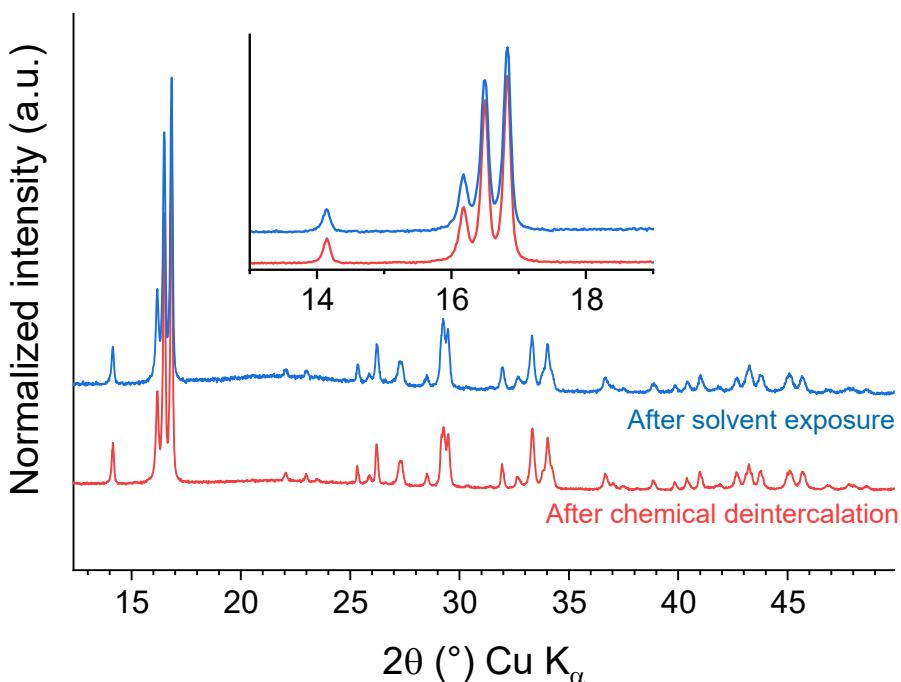
**Figure S2:** a) Isosurface Fourier difference map calculated from the Rietveld refinement of  $\text{K}_0\text{VPO}_4\text{F}$  drawn in 3D at isosurface  $0.7 \text{ e}\cdot\text{\AA}^{-3}$ . Negative electron densities are drawn in blue and positive in yellow. The slice in the (x,y) plane at  $z=0.18$  is represented for the case of K occupancy being refined (b) and K occupancy being set to 0.1, 0.2 or 1 (c). d) The comparison between both Fourier difference maps and profile line along x for  $y=0.5$  and  $z=0.18$  shows absolutely no residue, indicating the full deintercalation of K sites.

**Table S2:** Comparison of experimental (SXRD) and calculated cell parameters for  $K_0VPO_4F$ .

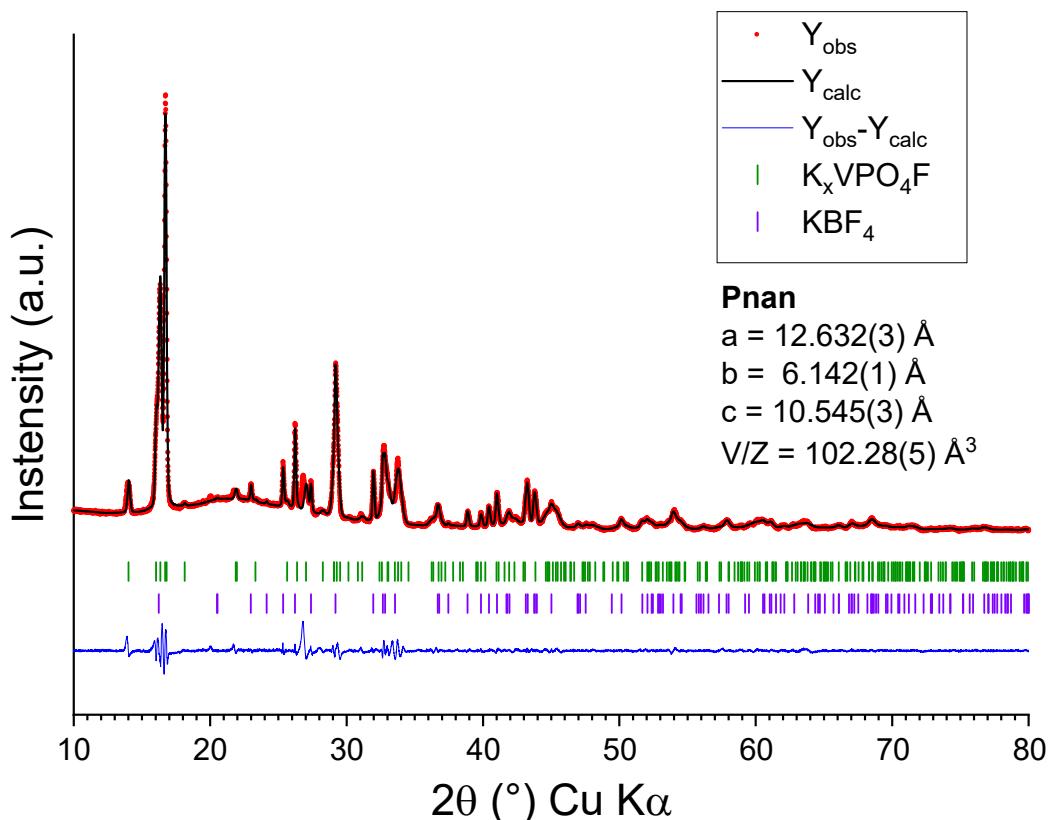
	a (Å)	b (Å)	c (Å)	V/Z (Å <sup>3</sup> )
Exp	12.504(1)	6.0875(5)	10.462(1)	99.544(3)
GGA+3eV	12.688	6.173	10.642	104.18
GGA+5eV	12.706	6.199	10.675	104.95



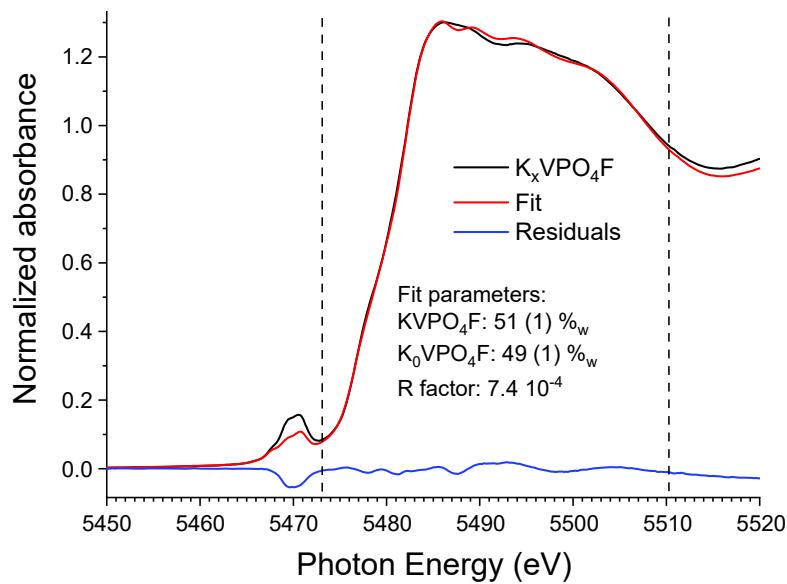
**Figure S3:** Spin density maps around P(1) (top) and P(2) (bottom) crystallographic sites with isosurface  $10^{-3}$  spin·Å<sup>-3</sup> calculated with  $U_{\text{eff}} = 5$  eV. The spin transfer mechanism is depicted with orbital schematic.



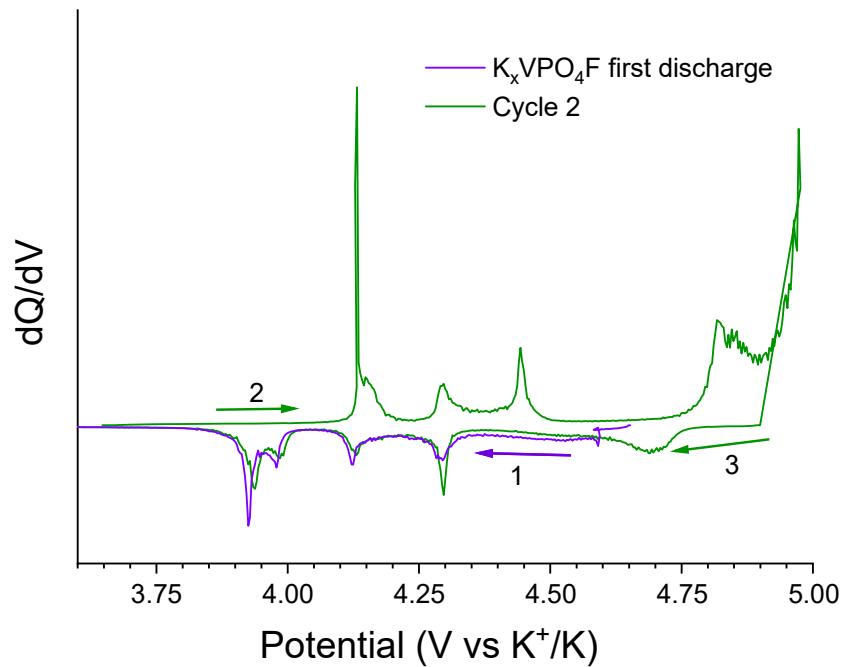
**Figure S4:** XRD patterns of  $\text{K}_0\text{VPO}_4\text{F}$  before and after solvent exposure.



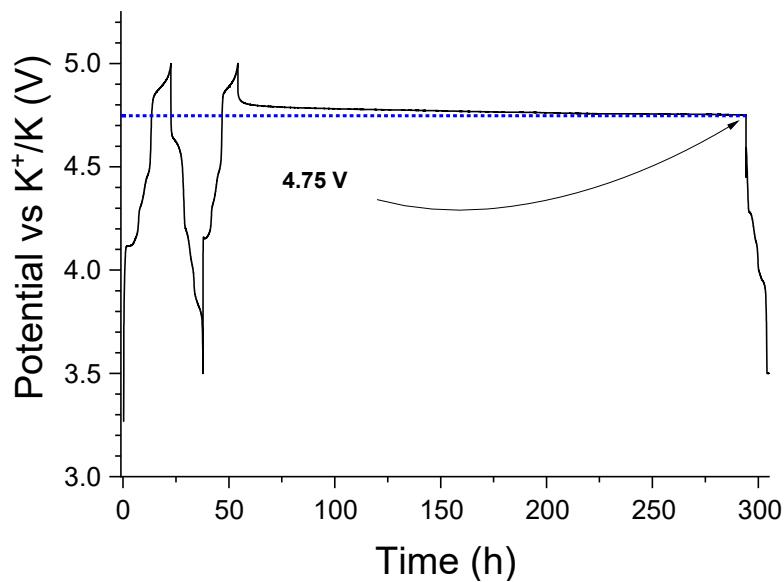
**Figure S5:** Two phases Lebail refinement of the compound recovered after immersion of  $\text{K}_0\text{VPO}_4\text{F}$  in the electrolyte ( $\text{K}_x\text{VPO}_4\text{F} + \text{KBF}_4$ ). The unit cell volume of  $\text{K}_x\text{VPO}_4\text{F}$  has expended by 2.8% compared to  $\text{K}_0\text{VPO}_4\text{F}$



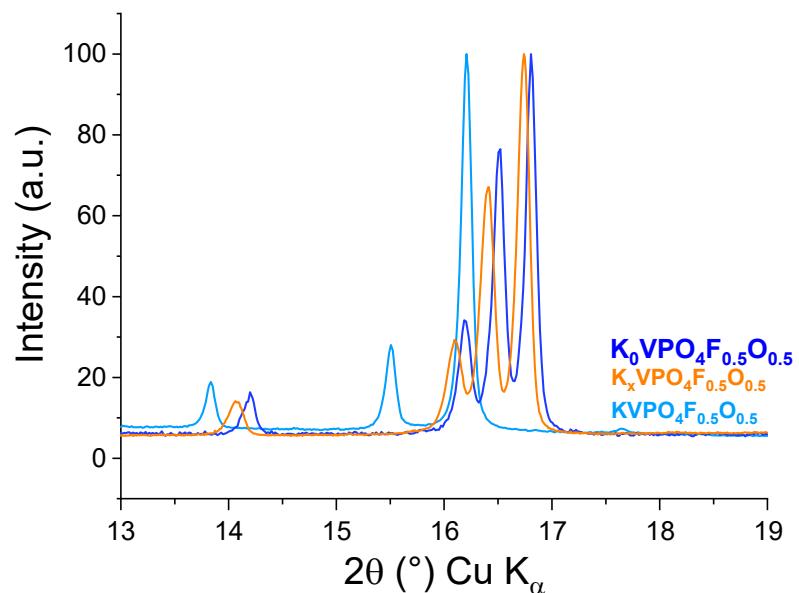
**Figure S6:** Linear combination fitting of the V K-edge of  $K_xVPO_4F$  using the spectra of KVPO<sub>4</sub>F and K<sub>0</sub>VPO<sub>4</sub>F as standards.



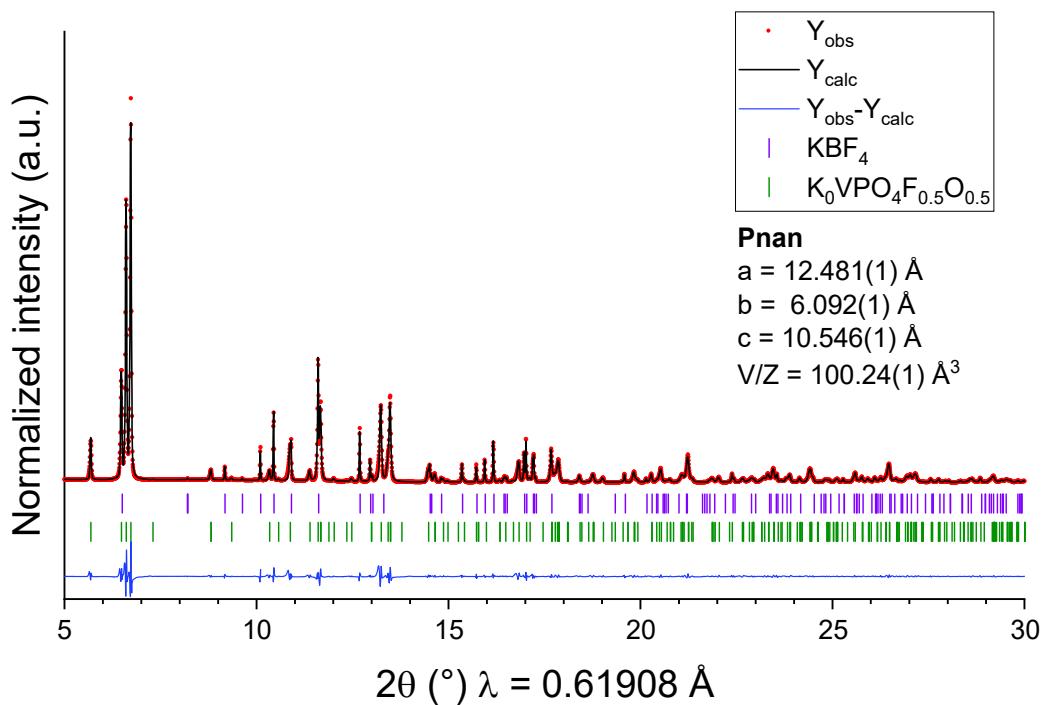
**Figure S7:** Derivative plot of galvanostatic cycling curves of  $K_xVPO_4F$  versus K metal at C/20.



**Figure S8:** Potential versus time plot of the 10 days OCV (after the second charge) to measure the corresponding self-discharge for KVPO<sub>4</sub>F versus K metal when charged up to 5 V vs.  $\text{K}^+/\text{K}$ .



**Figure S9:** XRD patterns of the first four Bragg reflections for pristine KVPO<sub>4</sub>F<sub>0.5</sub>O<sub>0.5</sub>, chemically deintercalated K<sub>0</sub>VPO<sub>4</sub>F<sub>0.5</sub>O<sub>0.5</sub>, and electrolyte exposed K<sub>x</sub>VPO<sub>4</sub>F<sub>0.5</sub>O<sub>0.5</sub>.



**Figure S10:** Full pattern matching refinement of chemically deintercalated  $\text{KVPO}_4\text{F}_{0.5}\text{O}_{0.5}$ , showing two phases  $\text{K}_0\text{VPO}_4\text{F}_{0.5}\text{O}_{0.5}$  and  $\text{KBF}_4$ .